

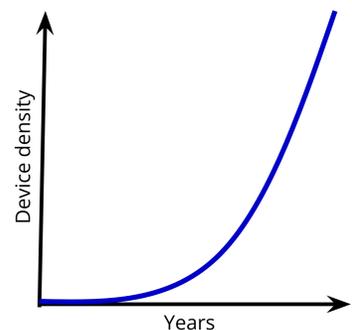


# DNA OR AN ELECTRONIC COMPONENT? THEY ARE CLOSER THAN YOU THINK

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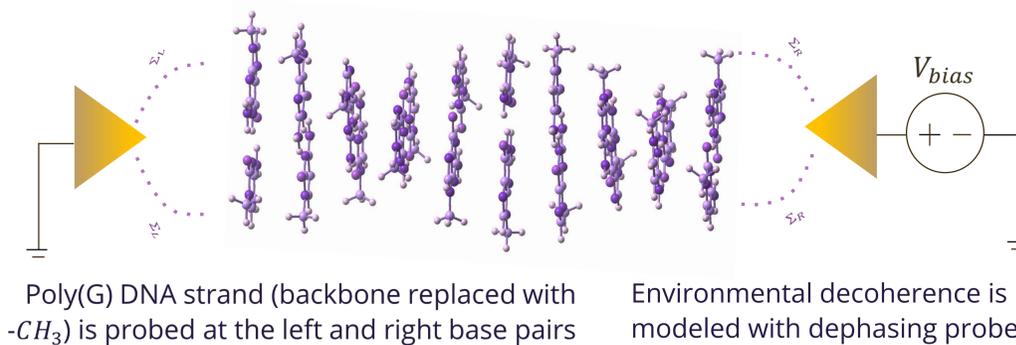
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## MOTIVATION



- Devices getting smaller
- DNA self-assembly has **atomic-level precision**
- See how to **engineer conductance** with different sequences
- Study electrical **properties**
- No inelastic scattering in previous studies

## SETUP

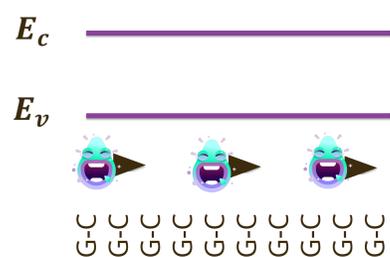


## KEY FINDINGS

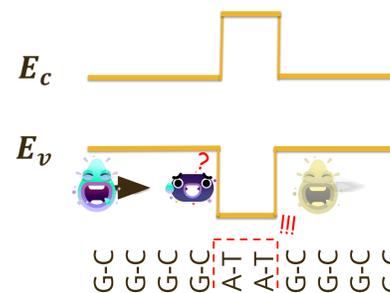
1. **Monotonic increase in current** without a barrier – purely coherent models fail to reproduce physical I-V behavior
2. Inclusion of a **hole barrier** suppresses hole-channel transmission by  $\sim 100x$ , demonstrating **sequence-controlled conductance switching**
3. Spatial LDOS maps reveal a well-defined intra-molecular **conduction pathway** — current cascades through stacked guanine bases via **sequential hopping**
4. Base-sequence programmability enables **bottom-up** design of molecular switches — a stepping stone toward **DNA-based nanoelectronic components**

## RESULTS

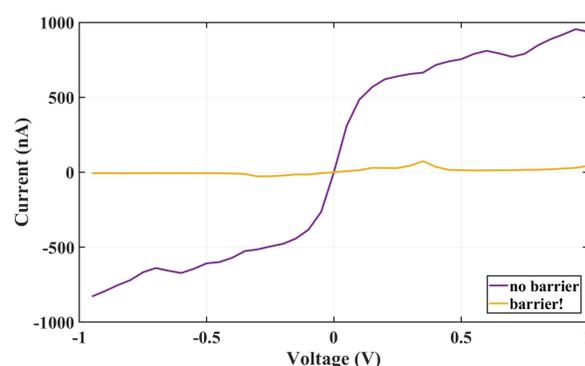
### MODEL APPROXIMATION



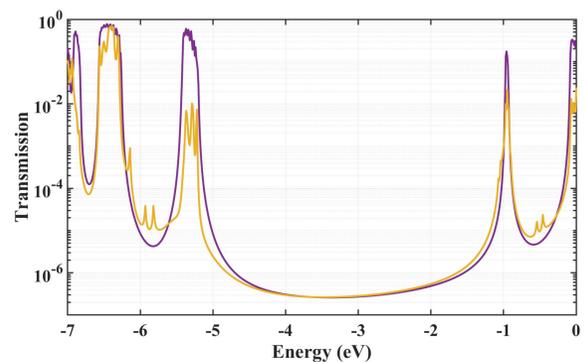
- G-C base pair has a low ionization energy, **conductance is observed to be high** compared to other nucleic acids



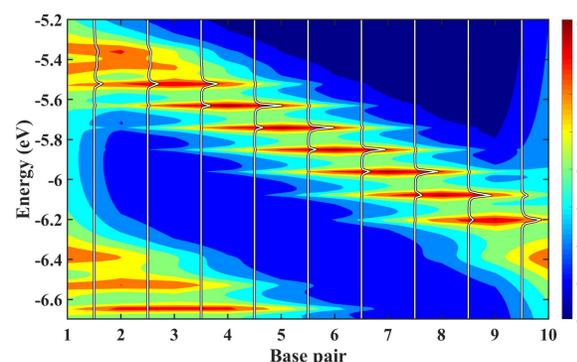
- A-T base pair acts as a **hole barrier**



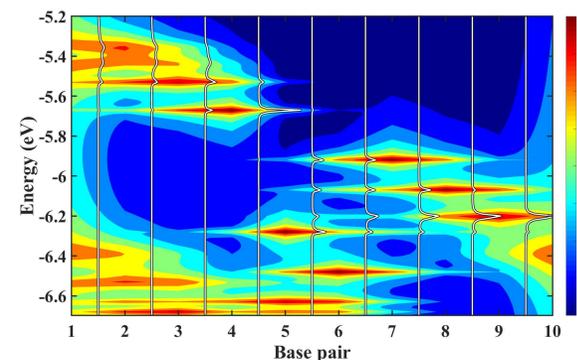
- Current-voltage curve shows current shuts off with sequence modification ✿



- Transmission with and without a barrier shows drastic decline at resonant energies 🌊



- Local density of states (LDOS) allows for a path for current. Current through DNA cross-sections is shown (no barrier) 🍀



- LDOS and current (amplified by 30 for visuals) with the hole barrier

## METHODS

- Transmission 
$$\begin{cases} [E - (H + \Sigma_L + \Sigma_R + \Sigma_B)]G^r = I \\ T(E) = \text{Tr}[\Gamma_L(E)G^r(E)\Gamma_R(E)G^a(E)] \end{cases}$$
- Current 
$$I_L = \frac{2q}{h} \sum_{j \in \text{probe}} \int T_{L,j}(E) * [f_L(E) - f_j(E)] dE$$
- Chemical potential of probes is determined by:

$$\begin{bmatrix} \mu_1 \\ \mu_2 \\ \vdots \\ \mu_N \end{bmatrix}_{itr+1} = \begin{bmatrix} \mu_1 \\ \mu_2 \\ \vdots \\ \mu_N \end{bmatrix}_{itr} - \alpha \begin{bmatrix} \frac{\partial I_1}{\partial \mu_1} & \frac{\partial I_1}{\partial \mu_2} & \dots & \frac{\partial I_1}{\partial \mu_N} \\ \frac{\partial I_2}{\partial \mu_1} & \frac{\partial I_2}{\partial \mu_2} & \dots & \frac{\partial I_2}{\partial \mu_N} \\ \vdots & \vdots & \ddots & \vdots \\ \frac{\partial I_N}{\partial \mu_1} & \frac{\partial I_N}{\partial \mu_2} & \dots & \frac{\partial I_N}{\partial \mu_N} \end{bmatrix}^{-1} * \begin{bmatrix} I_1 \\ I_2 \\ \vdots \\ I_N \end{bmatrix}_{itr}$$

## FUTURE WORK

- Characterize barrier-length dependence of tunneling regime — transition from direct to **Fowler-Nordheim tunneling**
- Model effects of a **phosphate backbone** with charged termination groups
- Observe the nucleotide behavior when an **additional electron** is added to the system



(Group Website)

